NSN 5962-00-137-5008

Memory Microcircuit - Page 1 of 1



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Body Length:

0.390 inches

Body Width:

0.390 inches

Body Height:

0.070 inches

Maximum Power Dissipation Rating:

307.2 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and monolithic and positive outputs and bipolar and negative outputs and unipolar and programmable and programmed

and w/enable and wire-or outputs

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Flat pack

Output Logic Form:

P-type metal oxide-semiconductor logic

Input Circuit Pattern:

12 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-20.0 volts power source and 8.3 volts power source

Time Rating Per Chacteristic:

900.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Test Data Document:

09128-d34005544 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

30 flat leads

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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